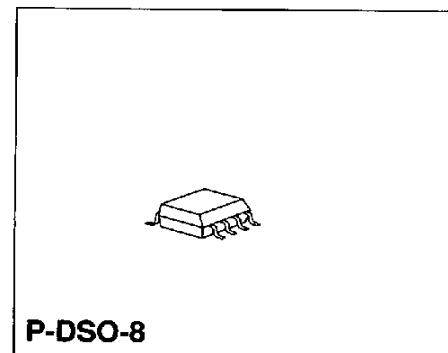


### Preliminary Data

Bipolar IC

### Features

- Low Current Consumption
- Wide Input Sensitivity
- Wide Input Frequency Range
- TTL/CMOS compatible MOD input
- Standby Mode
- Switchable divider ratios 64/65 or 128/129



### Applications

- With its very low (5.7 mA) current consumption the IC has been particularly designed for use in mobile communications. Furthermore, it can be switched to a low-power standby mode. Depending on the external network configuration, dividing ratios of 64/65 or 128/129 can be selected.

Type	Ordering Code	Package
PMB 2312	Q67000-A6039	P-DSO-8 (SMD)

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### Circuit Description

The symmetrical differential inputs of the IC may be connected asymmetrically. In this case the unused input must be RF-grounded with a capacitor (ca. 1.5 nF) with a low serial inductance.

Depending on the logic level at SW input the basic divide ratio of the ECL-stages is fixed to 1 : 64/65 or 1 : 128/129. The MOD input determines whether modulus 1 : n or 1 : n + 1 ( $n = 64$  or 128 according to SW-level) is active.

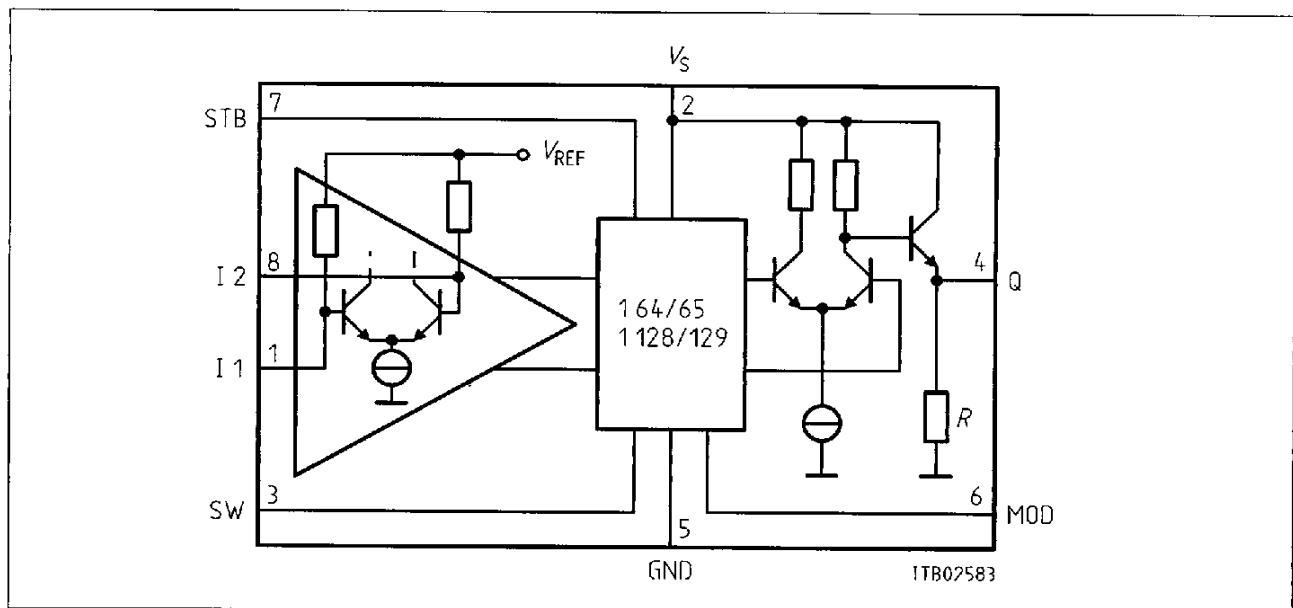
The IC can be switched to a low-power standby mode (input STB).

The MOD input is TTL/CMOS compatible.

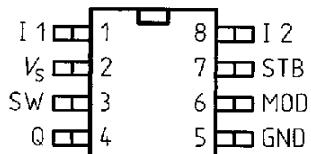
The open-emitter output is CMOS compatible according to the **application circuit**. The minimum logic swing is fixed to 1 Vpp.

### Function Table

Input Pin	Logic Level	Prescaler Function
SW	high = $V_s$ to $V_s$ low = GND to 0.8 V or open	1 : 64/65 1 : 128/129
MOD	high = 2.0 V to $V_s$ or open low = GND to 0.8 V	1 : 64/1 : 128 1 : 65/1 : 129
STB	high = $V_s - 0.1$ V to $V_s$ or open low = GND to 0.8 V	Divider Q = high, standby-mode

**Block Diagram****Pin Configuration**

(top view)

**Pin Definitions and Functions**

Pin No.	Symbol	Function
1	I1	Input I1
2	$V_s$	Supply voltage
3	SW	Divide ratio 1 : 64/65 – 1 : 128/129 control input
4	Q	Output
5	GND	Ground
6	MOD	Modulus 1 : n/n + 1 (n = 64 or 128) control input
7	STB	Standby mode control input
8	I2	Input I2

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**Electrical Characteristics****Absolute Maximum Ratings** $T_A = -40 \text{ to } 85 \text{ }^\circ\text{C}$ 

Parameter	Symbol	Limit Values		Unit
		min.	max.	
Supply voltage	$V_S$	-0.3	6	V
Input level (pin 1; pin 8)	$V_I$	1	5	V
Voltage swing (pin 1 to pin 8)	$V_{l18}$	-3	3	V
Input level (pin 3; pin 6; pin 7)	$V_{SW}, V_{MOD}, V_{STB}$	-0.3	6	V
Output level (pin 4)	$V_Q$		$V_S$	V
Output current (pin 4)	$-I_Q$		10	mA
Junction temperature	$T_J$		125	$^\circ\text{C}$
Storage temperature	$T_{stg}$	-65	125	$^\circ\text{C}$
Thermal resistance system-ambient	$R_{thSA}$		185	K/W

**Operating Range**

Supply Voltage	$V_S$	4.0	5.5	V
Input frequency	$f$	130	1100	MHz
Ambient temperature	$T_A$	-40	85	$^\circ\text{C}$

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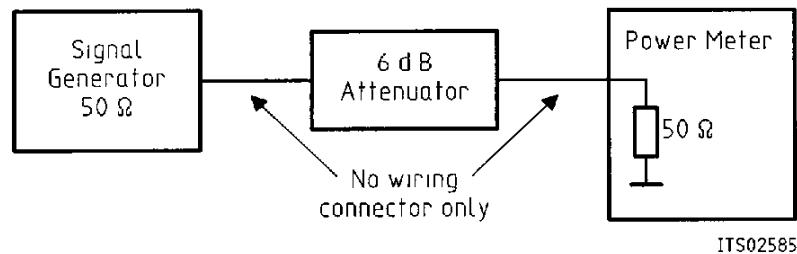
**AC/DC Characteristics** $V_S = 4.0$  to  $5.5$  V;  $T_A = -40$  to  $85$  °C; refer to test circuit

Parameter	Symbol	Limit Values			Unit	Test Condition
		min.	typ.	max.		
Supply current	$I_S$		5.7	7.4	mA	inputs RF-grounded, $V_S = 4.0$ V, $T_A = 25$ °C STB open, output open
Supply current	$I_S$		5.8	7.5	mA	inputs RF-grounded, $V_S = 5.0$ V, $T_A = 25$ °C STB open, output open
Supply current	$I_S$		5.9	7.7	mA	inputs RF-grounded, $V_S = 5.5$ V, $T_A = 25$ °C STB open, output open
Supply current in standby-mode	$I_{SSTB}$		0.3	0.45	mA	inputs RF-grounded, output open, STB = GND
Input level	$V_I$	25		400	mVrms	140 – 1000 MHz
Input sensitivity (diagram 2)		– 19		5	dBm	sine wave
Output logic swing	$V_Q$	1			Vpp	$C_L \leq 12$ pF
SW threshold voltage high	$V_{SWH}$	3.0		$V_S$	V	
SW threshold voltage low	$V_{SWL}$	GND		0.8	V	
SW input current high	$I_{SWH}$			100	µA	SW = $V_S$
SW input current low	– $I_{SWL}$			50	µA	SW = GND
MOD threshold voltage high	$V_{MODH}$	2.0		$V_S$	V	
MOD threshold voltage low	$V_{MODL}$	GND		0.8	V	
MOD input current high	$I_{MODH}$			50	µA	MOD = $V_S$
MOD input current low	– $I_{MODL}$			100	µA	MOD = GND
STB threshold voltage high	$V_{STBH}$	$V_S - 0.1$		$V_S$	V	
STB threshold voltage low	$V_{STBL}$			0.8	V	
STB input current high	$I_{STBH}$			50	µA	STB = $V_S$
STB input current low	– $I_{STBL}$			160	µA	STB = GND
Internal load resistance (see block diagram)	$R$		50		kΩ	

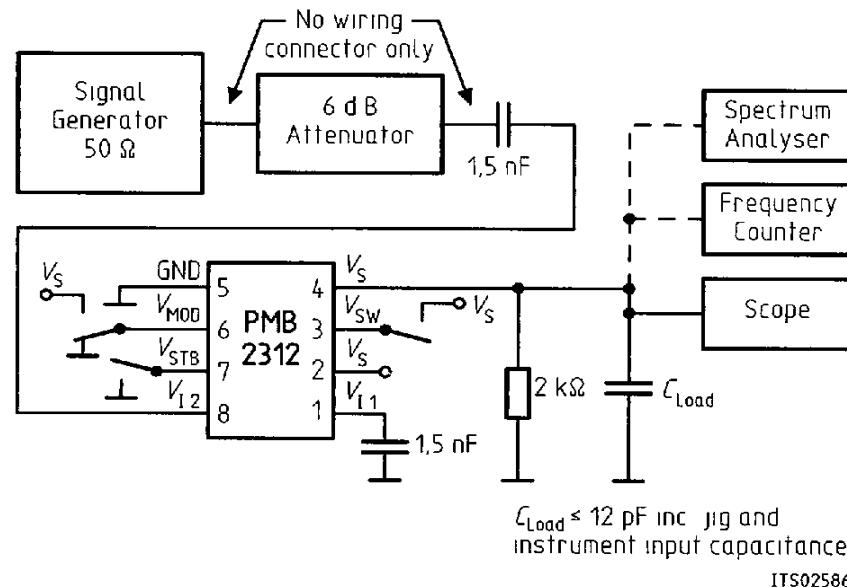
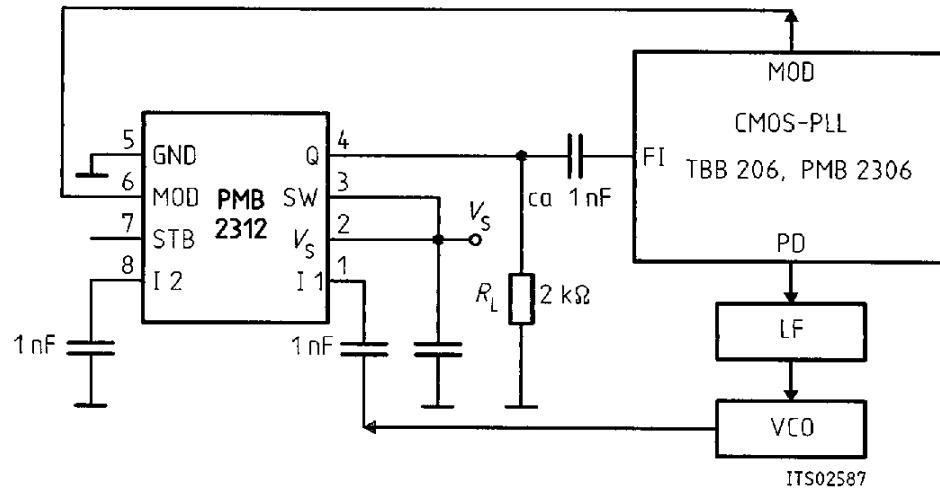
**Delay Times**

MOD setup time (diagram 1)	$t_{set}$			29	ns	
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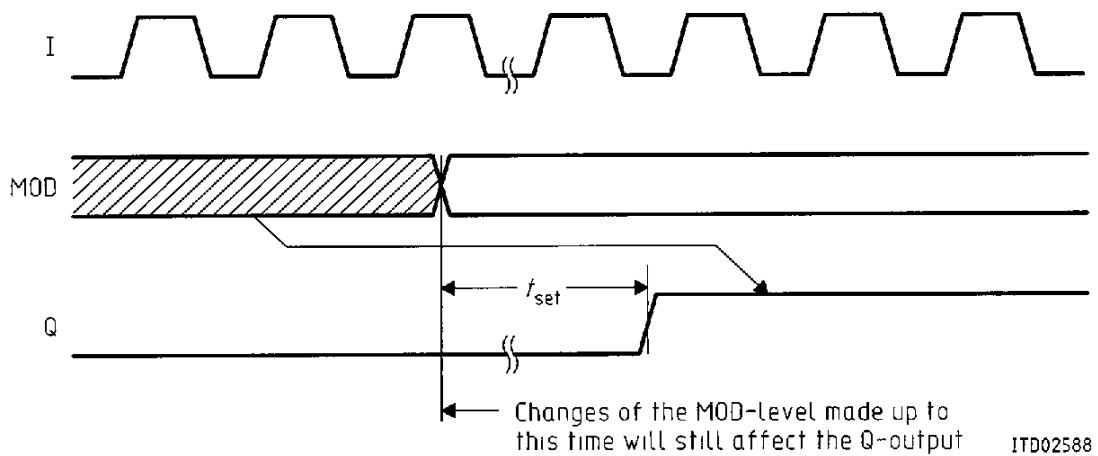
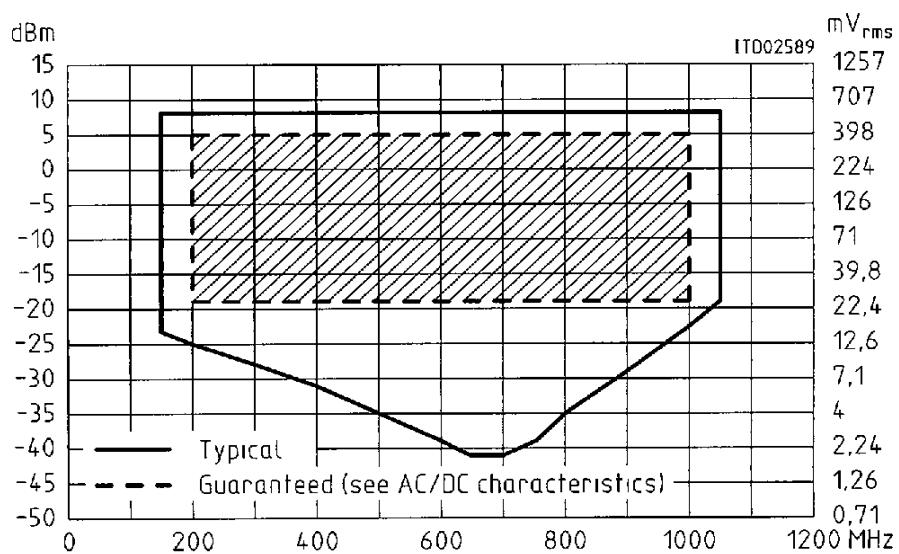
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**Test Circuits Calibration of the Signal Generator**

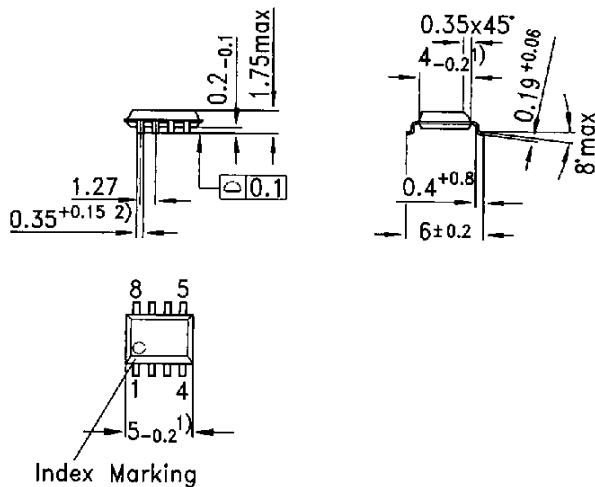
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**Input Sensitivity and Output Logic Swing Measurement****Application Circuit**

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**Diagram 1****Diagram 2**  
**Input Sensitivity**

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**Plastic Package, P-DSO-8 (SMD)  
(Plastic Dual Small Outline)**

- 1) Does not include plastic or metal protrusions of 0.15 max per side
- 2) Does not include dambar protrusion of 0.05 max per side

GPS05121

**Sorts of Packing**

Package outlines for tubes, trays etc. are contained in our  
Data Book "Package Information"

SMD = Surface Mounted Device

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Dimensions in mm

B115-H6626-  
G1-X-1600